

SMD Ultra Fast Recovery Rectifier

COMCHIP 
www.comchip.com.tw

CURM101 Thru CURM107

Reverse Voltage: 50 - 1000 Volts
Forward Current: 1.0 Amp

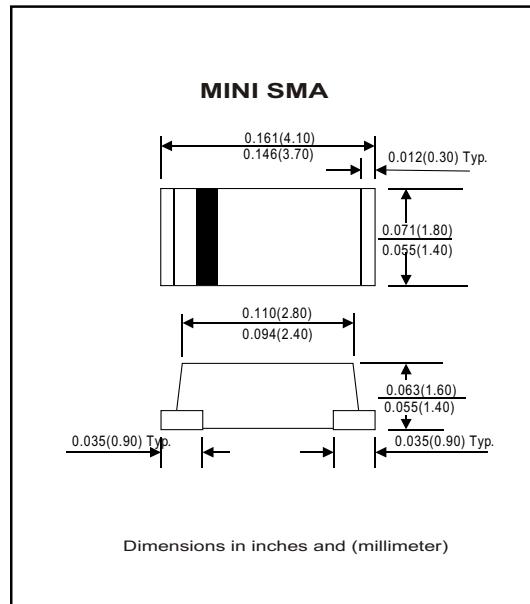


Features

- Ideal for surface mount applications
- Easy pick and place
- Plastic package has Underwriters Lab. flammability classification 94V-0
- Exceeds environmental standard MIL-S-19500/228
- Low leakage current

Mechanical data

- Case: Mini SMA/SOD-123 molded plastic
- Terminals: solderable per MIL-STD-750, method 2026
- Polarity: Color band denotes cathode end
- Mounting position: Any
- Approx. Weight: 0.04 gram



Maximum Ratings and Electrical Characteristics

Parameter	Symbol	CURM 101	CURM 102	CURM 103	CURM 104	CURM 105	CURM 106	CURM 107	Unit
Max. Repetitive Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Max. DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Max. RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Peak Surge Forward Current 8.3ms single halfsine-wave superimposed on rateload (JEDEC method)	I _{FSM}				30				A
Max. Average Forward Current	I _o				1.0				A
Max. Instantaneous Forward Current at 1.0 A	V _F			1.0		1.3		1.7	V
Reverse recovery time	T _{rr}			50			75		nS
Max. DC Reverse Current at Rated DC Blocking Voltage Ta=25°C Ta=100°C	I _R				5.0	50			uA
Typical. Thermal Resistance (Note 1)	R _{θJA}			42					°C/W
Operating Junction Temperature	T _j			-55 to +150					°C
Storage Temperature	T _{STG}			-55 to +150					°C

Note 1: Thermal resistance from junction to ambient.

SMD Ultra Fast Recovery Rectifier

COMCHIP 
www.comchip.com.tw

Rating and Characteristic Curves (CURM101 Thru CURM107)

Fig. 1 - Reverse Characteristics

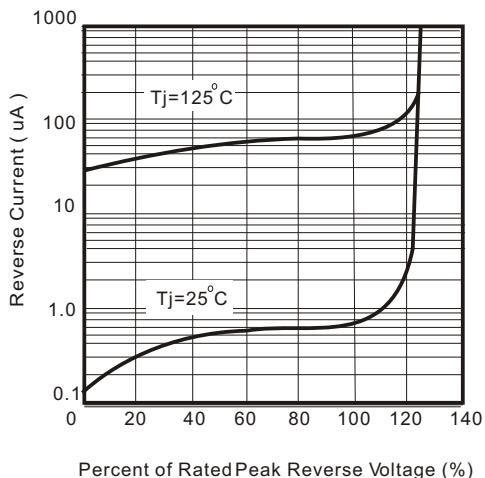


Fig. 2 - Forward Characteristics

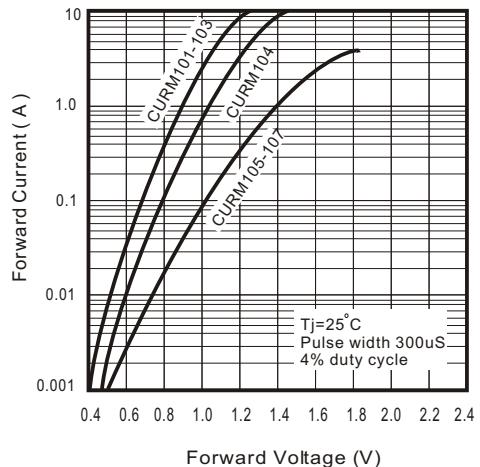


Fig. 3 - Junction Capacitance

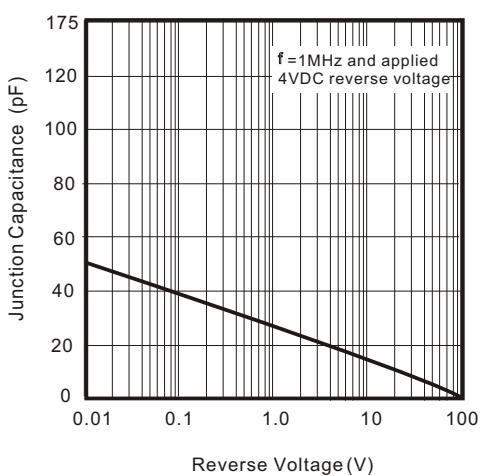


Fig. 4 - Non Repetitive Forward Surge Current

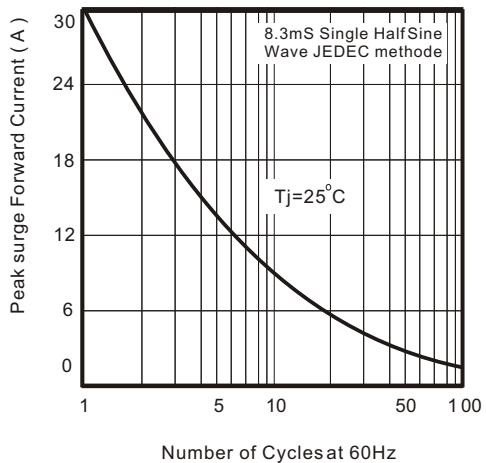


Fig. 5 - Test Circuit Diagram and Reverse Recovery Time Characteristics

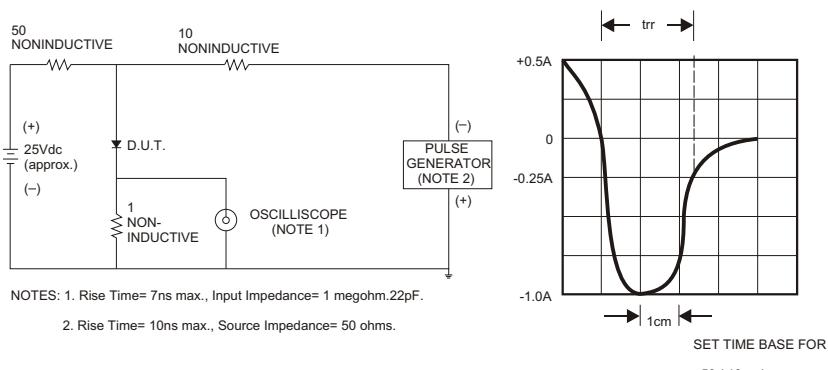


Fig. 6 - Current Derating Curve

